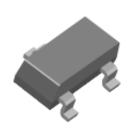
N-Channel 30-V (D-S) MOSFET

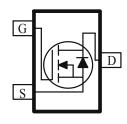
These miniature surface mount MOSFETs utilize High Cell Density process. Low r_{DS(on)} assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

•	Low r _{DS(on)} Provides Higher Efficiency and
	Extends Battery Life

- Miniature SOT-23 Surface Mount Package Saves Board Space
- High power and current handling capability
- Low side high current DC-DC Converter applications

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	I _D (A)	
30	$58 @ V_{GS} = 10V$	3.5	
30	$82 @ V_{GS} = 4.5V$	3.0	





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			30	V	
Gate-Source Voltage			±20	V	
C (D C (a	$T_A=25^{\circ}C$		3.5		
Continuous Drain Current ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$		2.8	A	
Pulsed Drain Current ^b	I_{DM}	16			
Continuous Source Current (Diode Conduction) ^a	I_S	1.25	A		
D D: a	$T_A=25^{\circ}C$	D	1.3	W	
Power Dissipation ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	L D	0.8	VV	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
	t <= 10 sec	$R_{ heta JA}$	100	°C/W	
Maximum Junction-to-Ambient ^a	Steady-State		166	°C/W	

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Parameter	Symbol Test Conditions		Limits			Unit
rarameter			Min	Тур	Max	Umt
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			1 25	uA
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	6			A
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 3.5 \text{ A}$ $V_{GS} = 4.5 \text{ V}, I_D = 3 \text{ A}$			58 82	mΩ
Forward Tranconductance ^A	$g_{ m fs}$	$V_{DS} = 15 \text{ V}, I_D = 3.5 \text{ A}$		6.9		S
Diode Forward Voltage	V_{SD}	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.8		V
Dynamic ^b						
Total Gate Charge	Q_{g}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		2.2		
Gate-Source Charge	Q_{gs}	$V_{DS} = 13 \text{ V}, V_{GS} = 4.3 \text{ V},$ $I_D = 3.5 \text{ A}$		0.5		nC
Gate-Drain Charge	Q_{gd}	I _D = 3.3 A		0.8		
Turn-On Delay Time	$t_{d(on)}$			16		
Rise Time	$t_{\rm r}$	$V_{DD} = 25 \text{ V}, R_L = 25 \Omega, I_D = 1 \text{ A},$		5		nS
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}$		23		113
Fall-Time	t_{f}			3		

Notes

a. Pulse test: $PW \le 300us duty cycle \le 2\%$.

b. Guaranteed by design, not subject to production testing.

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2

Typical Electrical Characteristics (N-Channel)

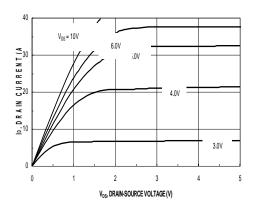


Figure 1. On-Region Characteristics

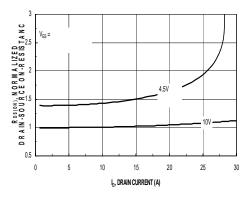


Figure 3. On Resistance Vs Vgs Voltage

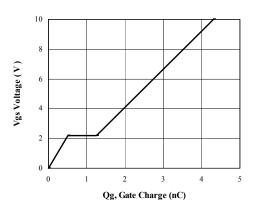


Figure 5. Gate Charge Characteristics

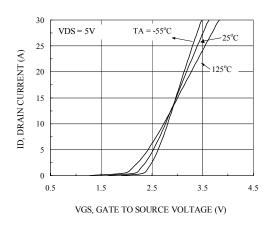


Figure 2. Body Diode Forward Voltage Variation with Source Current and Temperature

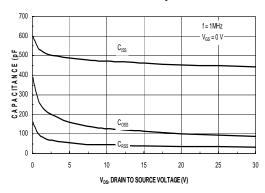


Figure 4. Capacitance Characteristics

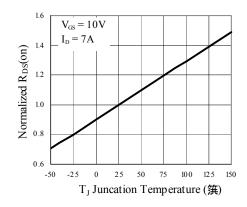
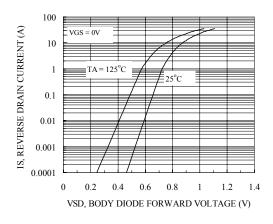


Figure 6. On-Resistance Variation with Temperature

Typical Electrical Characteristics (N-Channel)



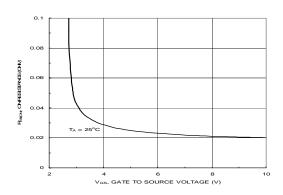


Figure 7. Transfer Characteristics

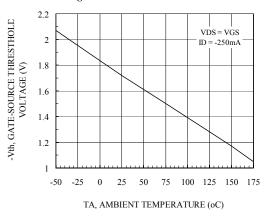


Figure 8. On-Resistance with Gate to Source Voltage

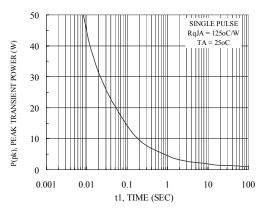


Figure 9. Vth Gate to Source Voltage Vs Temperature

Figure 10. Single Pulse Maximum Power Dissipation

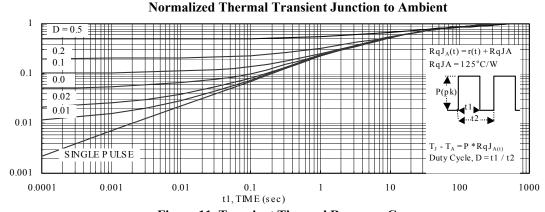
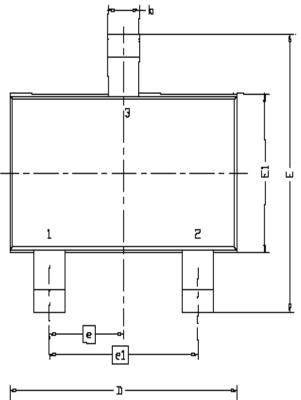
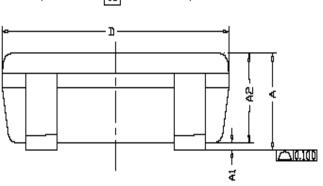


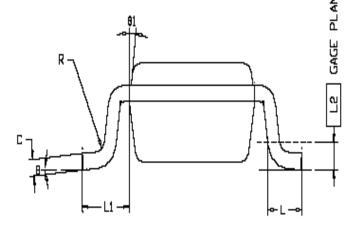
Figure 11. Transient Thermal Response Curve

Package Information



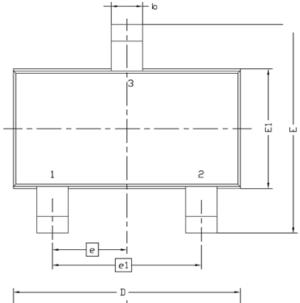
DIM.	MILLIMETERS				
יהודת	MIN	NDM	MAX		
Α	0.935	0.95	1.10		
A1	0.01		0.10		
A2	0.85	0.90	0.925		
р	0.30	0.40	0.50		
С	0.10	0.15	0,25		
D	2.70	2.90	3.10		
П	2.60	2.80	3.00		
E1	1.40	1.60	1.80		
6	0.95 BSC				
el	1	.90 BS	C		
Г	0.30	0.40	0.60		
L1	0.60REF				
LZ	0,25BSC				
R	0.10				
θ	Q+	4*	8,		
81	7"N□M				



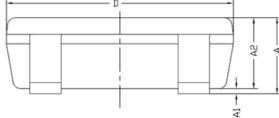


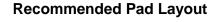
Analog Power SOT-23

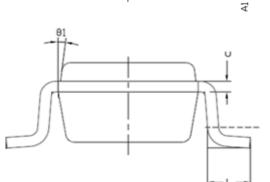
Package Information

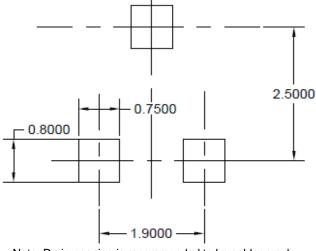


Symbol	MILLIMETERS		
Symbol	MIN	MAX	
Α	0.8	1.2	
A1	0	0.1	
A2	0.7	1.1	
b	0.3	0.5	
С	0.1	0.2	
D	2.7	3.1	
Е	2.6	3	
E1	1.4	1.8	
е	0.95 BSC		
e1	1.9 BSC		
L	0.3	0.6	
θ1	7° NOM		









Note: Drain opening is recommended to be solder mask defined in a copper fill for improved thermal performance

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